NSN 5961-01-186-9141

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-186-9141 **Inclosure Material:** Metal **Mounting Facility Quantity: Mounting Method:** Unthreaded hole **Features Provided:** Burn in **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 100.0 repetitive peak reverse voltage **Current Rating Per Characteristic:** 200.00 amperes forward current, average blank Shelf Life: N/a **Unit Of Measure:** Demilitarization: Yes - demil/mli

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